NSN 5961-00-355-4793

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View Online at https://aerobasegroup.com/nsn/5961-00-355-4793 **Inclosure Material:** Metal and plastic **Overall Length:** Between 0.660 inches and 0.780 inches **Terminal Length:** Between 0.100 inches and 0.155 inches **Overall Height:** 0.180 inches **Overall Width:** Between 0.220 inches and 0.280 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 70.0 collector to base voltage, dc all transistor and 45.0 collector to emitter voltage/static/base open all transistor and 70.0 collector to emitter voltage, dc with base short-circuited to emitter all transistor and 6.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** 1.50 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 2000.0 milliwatts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Precious Material And Location:** Terminal surface option gold **Precious Material:** Gold **Test Data Document:** 07187-4006583 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 14 pin Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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